INTEGRATED CIRCUITS

DATA SHEET

74ALVCH16540

2.5V/3.3V 16-bit buffer/line driver, inverting, 5V input tolerant (3-State)

Product specification Supersedes data of 1996 Feb 07 IC24 Data Handbook





Philips Semiconductors Product specification

16-bit buffer/line driver, inverting, 5V input tolerant (3-State)

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FEATURES

- Wide supply voltage range of 1.2 V to 3.6 V
- Complies with JEDEC standard no. 8-1A
- CMOS low power consumption
- MULTIBYTETM flow-through standard pin-out architecture
- Low inductance multiple V_{CC} and ground pins for minimum noise and ground bounce
- Direct interface with TTL levels
- Bus hold on all data inputs eliminates the need for external pull-up resistors to hold unused inputs
- Output drive capability 50Ω transmission lines @ 85°C

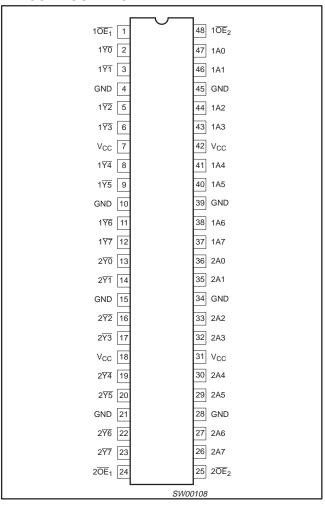
DESCRIPTION

The 74ALVCH16540 is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

The 74ALVCH16540 is a 16-bit inverting buffer/line driver with 3-State outputs. The 3-State outputs are controlled by the output enable inputs $1\overline{OE}_n$ and $2\overline{OE}_n$. A HIGH on $n\overline{OE}_n$ causes the outputs to assume a high impedance OFF-state.

Active bus hold circuitry is provided to hold unused or floating data inputs at a valid logic level. This feature eliminates the need for external pull-up or pull-down resistors. The device can be used as four 4-bit buffers, two 8-bit buffers or one 16-bit buffer.

PIN CONFIGURATION



QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5$ ns

SYMBOL	PARAMETER	CONE	DITIONS	TYPICAL	UNIT
	Propagation delay 1An to 1Yn;	$C_L = 50pF$ $V_{CC} = 3.3V$		1.8	ns
t _{PHL} /t _{PLH}	2An to 2Yn	C _L = 30pF V _{CC} = 2.5V	1.8	ns	
C _I	Input capacitance			5.0	pF
C	Power dissipation capacitance per buffer	$V_I = GND \text{ to } V_{CC}^{-1}$	Outputs enabled	26	pF
C _{PD}	rower dissipation capacitance per buller	AL = GIAD 10 ACC.	Outputs disabled	5	pF

NOTES:

 C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_0)$ where: $f_i = \text{input frequency in MHz; } C_L = \text{output load capacitance in pF;}$

 f_0 = output frequency in MHz; V_{CC} = supply voltage in V;

 $\Sigma (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER		
48-Pin Plastic SSOP Type III	–40°C to +85°C	74ALVCH16540 DL	ACH16540 DL	SOT370-1		
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74ALVCH16540 DGG	ACH16540 DGG	SOT362-1		

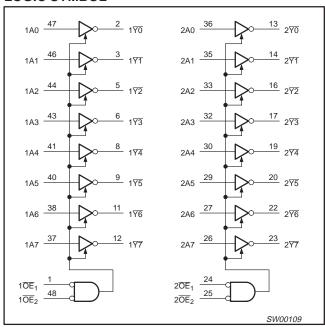
16-bit buffer/line driver, inverting, 5V input tolerant (3-State)

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PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 24	n OE ₁	Output enable input (active LOW)
2, 3, 5, 6, 8, 9, 11, 12	1Y0 to 1Y7	Data outpute
13, 14, 16, 17, 19, 20, 22, 23	2Y0 to 2Y7	Data outputs
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V _{CC}	Positive supply voltage
25, 48	n OE ₂	Output enable input (active LOW)
36, 35, 33, 32, 30, 29, 27, 26	2A0 to 2A7	Data inpute
47, 46, 44, 43, 41, 40, 38, 37	1A0 to 1A7	Data inputs

LOGIC SYMBOL



FUNCTION TABLE

	INPUTS		OUTPUT
n OE 1	nOE ₂	nAn	nYn
L	L	L	Н
L	L	Н	L
Х	Н	Х	Z
Н	Х	Х	Z

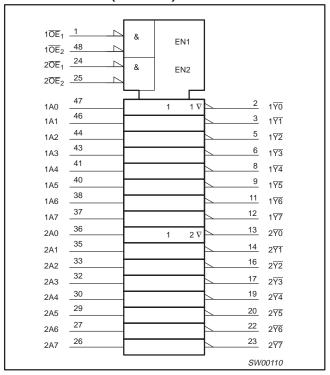
H = HIGH voltage level

L = LOW voltage level

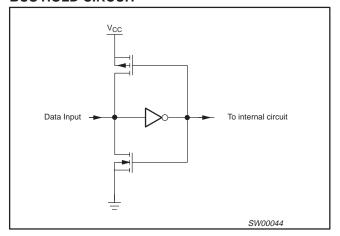
X = don't care

Z = high impedance OFF-state

LOGIC SYMBOL (IEEE/IEC)



BUS HOLD CIRCUIT



16-bit buffer/line driver, inverting, 5V input tolerant (3-State)

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIM	IITS	UNIT	
STWIBUL	PARAMETER	CONDITIONS	MIN	MAX	ONII	
	DC supply voltage 2.5V range (for max. speed performance)		2.3	2.7		
V _{CC}	DC supply voltage 3.3V range (for max. speed performance)		3.0	3.6	V	
	DC supply voltage (for low-voltage applications)		1.2	3.6		
V	DC Input voltage range	For data input pins	0	V _{CC}	V	
V _I	DC Input voltage range	For control pins	0	5.5	V	
Vo	DC output voltage range		0	V _{CC}	V	
T _{amb}	Operating free-air temperature range		-40	+85	°C	
t _r , t _f	Input rise and fall times	$V_{CC} = 2.3 \text{ to } 3.0 \text{V}$ $V_{CC} = 3.0 \text{ to } 3.6 \text{V}$	0 0	20 10	ns/V	

ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V _I < 0	- 50	mA
VI	DC input voltage	For control pins and data inputs of ALVC parts ²	-0.5 to +5.5	V
		For data inputs of ALVCH parts ²	-0.5 to V _{CC} +0.5	1
I _{OK}	DC output diode current	$V_{O} > V_{CC}$ or $V_{O} < 0$	±50	mA
Vo	DC output voltage	Note 2	-0.5 to V _{CC} +0.5	V
Io	DC output source or sink current	$V_O = 0$ to V_{CC}	±50	mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		±100	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package –plastic medium-shrink SO (SSOP) –plastic mini-pack (TSSOP)	For temperature range: -40 to +125 °C above +55°C derate linearly with 11.3 mW/K above +55°C derate linearly with 8 mW/K	850 600	mW

NOTES:

^{1.} Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

^{2.} The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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DC ELECTRICAL CHARACTERISTICS

		L	IMITS]		
SYMBOL	PARAMETER	TEST CONDITIO	Temp = -	40°C to	+85°C	UNI	
			MIN	TYP ¹	MAX		
		V _{CC} = 1.2V		Vcc			
V_{IH}	HIGH level Input voltage	V _{CC} = 2.3 to 2.7V		1.7			1 v
		V _{CC} = 2.7 to 3.6V		2.0			1
		V _{CC} = 1.2V				GND	Г
V_{IL}	LOW level Input voltage	V _{CC} = 2.3 to 2.7V				0.7	1 v
		V _{CC} = 2.7 to 3.6V				0.8	1
		$V_{CC} = 2.3V$; $V_I = V_{IH}$ or V_{IL} ; $I_O =$: –1mA	V _{CC} _0.3			Г
		$V_{CC} = 2.3V$; $V_I = V_{IH}$ or V_{IL} ; $I_O =$: –8mA	V _{CC} _0.5			1
V_{OH}	HIGH level output voltage	$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; $I_O =$: –12mA	V _{CC} _0.5			1 ∨
		$V_{CC} = 2.3/3.0V; V_I = V_{IH} \text{ or } V_{IL};$	$I_{O} = -100 \mu A$	V _{CC} -0.2	V _{CC}		1
		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O =$	-24mA	V _{CC} -1.0			1
		$V_{CC} = 2.3V$; $V_I = V_{IH}$ or V_{IL} ; $I_O =$: 1mA			0.40	Г
		$V_{CC} = 2.3V; V_I = V_{IH} \text{ or } V_{IL}; I_O =$	· 8mA			0.60	1
V_{OL}	LOW level output voltage	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O =$: 12mA			0.40	1 \
		$V_{CC} = 2.3/3.0V; V_I = V_{IH} \text{ or } V_{IL};$	I _O = 100μA			0.20	1
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O =$	24mA			0.55	1
		$V_{CC} = 3.6V; V_I = 5.5V \text{ or GND}$	Control pins		± 0.1	±5	Г
t _l	Input leakage current	$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND	Data input pins		±0.1	±5	μ
I _{IHZ} /I _{ILZ}	Input current for common I/O pins	$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND			±0.1	±15	μ
	3-State output OFF-state current	$V_{CC} = 3.6V$; $V_I = V_{IH}$ or V_{IL} ; V_O	= V _{CC} or GND		0.1	±10	Г
I_{OZ}	3-State output OFF-state current	$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; V_O	= V _{CC} or GND		0.1	±5	μ
	Quiescent supply current	$V_{CC} = 3.6V; V_{I} = V_{CC} \text{ or GND}; I_{CC} = 3.6V; V_{CC} $	O = 0		0.2	40	Г
Icc	Quiescent supply current	$V_{CC} = 2.7V; V_{I} = V_{CC} \text{ or GND}; I_{CC} = 2.7V; V_{I} = V_{CC} \text{ or GND}; I_{CC} = 2.7V; V_{I} = V_{CC} \text{ or GND}; I_{CC} = 2.7V; V_{I} = V_{CC} \text{ or GND}; I_{CC} = 2.7V; V_{I} = V_{CC} \text{ or GND}; I_{CC} = 2.7V; V_{I} = V_{CC} \text{ or GND}; I_{CC} = 2.7V; V_{I} = V_{CC} \text{ or GND}; I_{CC} = 2.7V; V_{I} = V_{CC} \text{ or GND}; I_{CC} = 2.7V; V_{I} = V_{CC} \text{ or GND}; I_{CC} = 2.7V; V_{CC} = 2.7V; V$	O = 0		0.2	20	μ
A1	Additional quiescent supply current per control pin	$V_{CC} = 2.7V \text{ to } 3.6V; V_I = V_{CC} - 0.000$	0.6V; I _O = 0		5	500	μ
Δl _{CC}	Additional quiescent supply current per data I/O pin	$V_{CC} = 2.7V \text{ to } 3.6V; V_I = V_{CC} - 0.000$	0.6V; $I_0 = 0$		150	750	μ,
IBHL	Bus hold LOW sustaining current	$V_{CC} = 2.3V; V_I = 0.7V$		45			μ,
	2011 2011 2011	$V_{CC} = 3.0V; V_I = 0.8V$		75			
IBHH	Bus hold HIGH sustaining current	$V_{CC} = 2.3V; V_I = 1.7V$		-45			μ
	245 Hold File Front Guotalining Guiront	$V_{CC} = 3.0V; V_I = 2.0V$		- 75			μ
IBHLO	Bus hold LOW overdrive current	$V_{CC} = 2.7V$		300			μ,
IDITILO	Dao noia Eovy overanye canent	V _{CC} = 3.6V		450			μ.
IBHHO	Bus hold HIGH overdrive current	V _{CC} = 2.7V		-300			μ
יוו וטו	Bus note in or i overalive current	V _{CC} = 3.6V		-450			"

NOTES:

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^{1.} All typical values are at V_{CC} = 3.3V and T_{amb} = $25^{\circ}C.$

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AC CHARACTERISTICS FOR $V_{CC} = 3.0V$ TO 3.6V RANGE AND $V_{CC} = 2.7V$

GND = 0V; $t_r = t_f \le 2.5 \text{ns}$; $C_L = 50 \text{pF}$

					LIM	ITS		
SYMBOL	PARAMETER	WAVEFORM	V _C	$_{\sf C}$ = 3.0 \pm 0.	3V	V _{CC} =	UNIT	
			MIN	TYP ¹	MAX	TYP	MAX]
t _{PHL} /t _{PLH}	Propagation delay 1An to 1Yn; 2An to 2Yn	4		1.8	3.0	2.1	3.6	ns
t _{PZH} /t _{PZL}	3-State output enable time 10En to 1Yn; 20En to 2Yn	5, 6		2.1	3.8	2.9	4.7	ns
t _{PHZ} /t _{PLZ}	3-State output disable time 10En to 1Yn; 20En to 2Yn	5, 6		2.7	4.1	3.2	4.5	ns

NOTE:

AC CHARACTERISTICS FOR V_{CC} = 2.3V TO 2.7V RANGE AND V_{CC} < 2.3V

GND = 0V; $t_r = t_f \le 2.0 \text{ns}$; $C_L = 30 \text{pF}$

					LIM	ITS		
SYMBOL	PARAMETER	WAVEFORM	V _{CC}	= 2.3 to 2	2.7V	V _{CC} = 1.8V	V _{CC} = 1.2V	UNIT
			MIN	TYP ¹	MAX	TYP	MAX	
t _{PHL} /t _{PLH}	Propagation delay 1An to 1Yn; 2An to 2Yn	4		1.8	3.2	3.1	6.0	ns
t _{PZH} /t _{PZL}	3-State output enable time 10En to 1Yn; 20En to 2Yn	5, 6		2.5	4.4	4.3	8.9	ns
t _{PHZ} /t _{PLZ}	3-State output disable time 10En to 1Yn; 20En to 2Yn	5, 6		2.2	3.8	3.6	6.4	ns

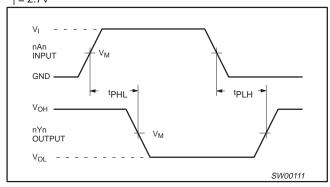
NOTE:

AC WAVEFORMS FOR V_{CC} = 3.0V TO 3.6V AND V_{CC} = 2.7V RANGE

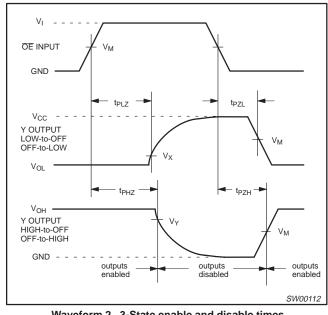
 $V_{M} = 1.5 \text{ V}$ $V_X = V_{OL} + 0.3V$

 $V_Y = V_{OH} - 0.3V$ V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.

 $_{1} = 2.7 V$



Waveform 1. Input (An) to output (Yn) propagation delay times



Waveform 2. 3-State enable and disable times

^{1.} All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25$ °C.

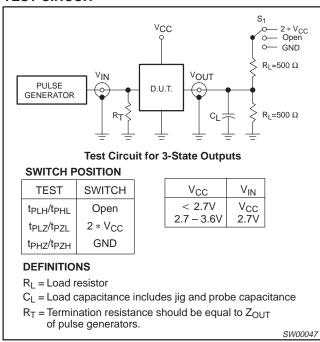
^{1.} All typical values are at V_{CC} = 2.5V and T_{amb} = 25°C.

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TEST CIRCUIT

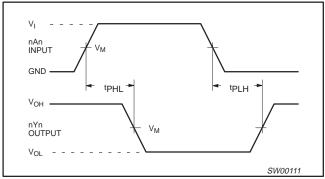


Waveform 3. Load circuitry for switching times

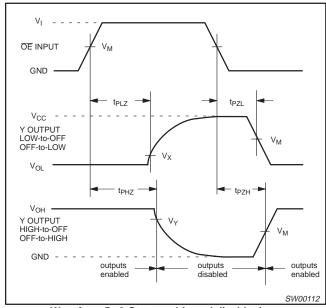
AC WAVEFORMS FOR V_{CC} = 2.3V TO 2.7V AND V_{CC} < 2.3V RANGE

 $V_M = 0.5 * V_{CC} \\ V_X = V_{OL} + 0.15V \\ V_Y = V_{OH} - 0.15V \\ V_{OL} \text{ and } V_{OH} \text{ are the typical output voltage drop that occur with the}$ output load.

V_I = V_{CC}



Waveform 4. Input (An) to output (Yn) propagation delay times



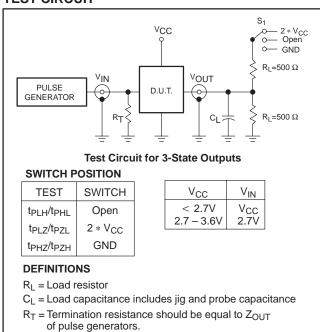
Waveform 5. 3-State enable and disable times

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TEST CIRCUIT



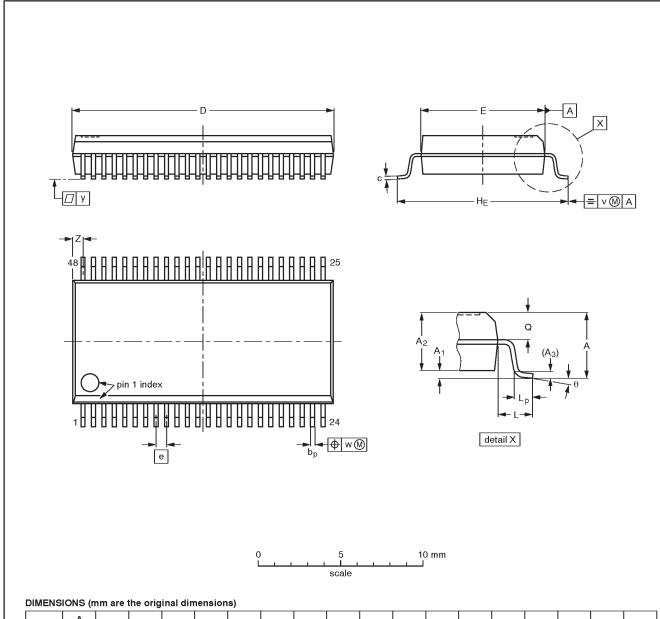
Waveform 6. Load circuitry for switching times

2.5V/3.3V 16-bit buffer/line driver, inverting, 5V input tolerant (3-State)

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SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1



UNIT	A max.	Α1	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	16.00 15.75	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

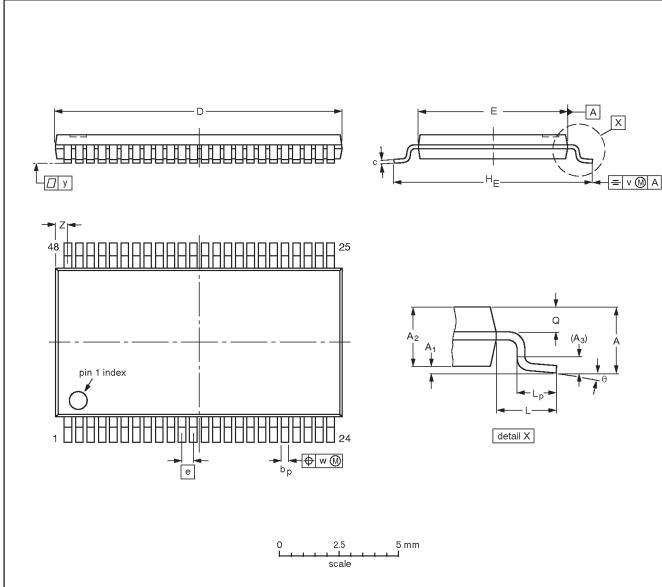
OUTLINE		EUROPEAN	ISSUE DATE					
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE		
SOT370-1		MO-118AA				93-11-02 95-02-04		

2.5V/3.3V 16-bit buffer/line driver, inverting, 5V input tolerant (3-State)

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TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1mm

SOT362-1



DIMENSIONS (mm are the original dimensions).

UNIT	A max.	A ₁	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	z	θ
mm	1.2	0.15 0.05	1.05 0.85	0.25	0.28 0.17	0.2 0.1	12.6 12.4	6.2 6.0	0.5	8.3 7.9	1	0.8 0.4	0.50 0.35	0.25	0.08	0.1	0.8 0.4	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE
	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT362-1		MO-153ED				-93-02-03 95-02-10

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DEFINITIONS						
Data Sheet Identification	Product Status	Definition				
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.				
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.				
Product Specification	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.				

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